

Peizhe Tang

List of Publications by Year in descending order

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44
papers

4,167
citations

218677

26
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254184

43
g-index

45
all docs

45
docs citations

45
times ranked

5954
citing authors

#	ARTICLE	IF	CITATIONS
1	Light-induced emergent phenomena in 2D materials and topological materials. Nature Reviews Physics, 2022, 4, 33-48.	26.6	94
2	Single-Atom Reversible Lithiophilic Sites toward Stable Lithium Anodes. Advanced Energy Materials, 2022, 12, .	19.5	49
3	Evolution of Electronic Structure in Pristine and Rb-Reconstructed Surfaces of Kagome Metal RbV_3Sb_5 . Nano Letters, 2022, 22, 918-925.	9.1	17
4	Orbital-selective two-dimensional superconductivity in H_2NbS_2 . Physical Review Research, 2022, 4, .	3.6	5
5	Chemical Potential Switching of the Anomalous Hall Effect in an Ultrathin Noncollinear Antiferromagnetic Metal. Advanced Materials, 2022, 34, e2200487.	21.0	7
6	Unconventional excitonic states with phonon sidebands in layered silicon diphosphide. Nature Materials, 2022, 21, 773-778.	27.5	20
7	Spin manipulation by giant valley-Zeeman spin-orbit field in atom-thick WSe ₂ . Applied Physics Reviews, 2022, 9, .	11.3	10
8	Anomalous thickness dependence of Curie temperature in air-stable two-dimensional ferromagnetic 1T-CrTe ₂ grown by chemical vapor deposition. Nature Communications, 2021, 12, 809.	12.8	196
9	Two-dimensional intrinsic ferromagnetic monolayer transition metal oxyhydroxide. Physical Review B, 2021, 103, .	3.2	10
10	Topological phase transitions induced by disorder in magnetically doped Bi_2Se_3 thin films. Physical Review B, 2020, 102, .	3.2	6
11	Berry curvature engineering by gating two-dimensional antiferromagnets. Physical Review Research, 2020, 2, .	3.6	22
12	Light-induced anomalous Hall effect in massless Dirac fermion systems and topological insulators with dissipation. New Journal of Physics, 2019, 21, 093005.	2.9	34
13	Microscopic theory for the light-induced anomalous Hall effect in graphene. Physical Review B, 2019, 99, .	3.2	117
14	Spatially controlled doping of two-dimensional SnS ₂ through intercalation for electronics. Nature Nanotechnology, 2018, 13, 294-299.	31.5	269
15	Reversible and selective ion intercalation through the top surface of few-layer MoS ₂ . Nature Communications, 2018, 9, 5289.	12.8	119
16	Visualizing topological edge states of single and double bilayer Bi supported on multibilayer Bi(111) films. Physical Review B, 2018, 98, .	3.2	40
17	Learning atoms for materials discovery. Proceedings of the National Academy of Sciences of the United States of America, 2018, 115, E6411-E6417.	7.1	138
18	Dirac semimetal phase in hexagonal LiZnBi. Physical Review B, 2017, 96, .	3.2	26

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19	Gated tuned superconductivity and phonon softening in monolayer and bilayer MoS ₂ . Npj Quantum Materials, 2017, 2, .	5.2	33
20	Multiple Types of Topological Fermions in Transition Metal Silicides. Physical Review Letters, 2017, 119, 206402.	7.8	298
21	Magnetic order induces symmetry breaking in the single-crystalline orthorhombic CuMnAs semimetal. Physical Review B, 2017, 96, .	3.2	22
22	Dirac fermions in an antiferromagnetic semimetal. Nature Physics, 2016, 12, 1100-1104.	16.7	216
23	Stable Dirac semimetal in the allotropes of group-IV elements. Physical Review B, 2016, 93, .	3.2	13
24	Topological Superconductivity on the Surface of Fe-Based Superconductors. Physical Review Letters, 2016, 117, 047001.	7.8	198
25	Heavy Dirac fermions in a graphene/topological insulator hetero-junction. 2D Materials, 2016, 3, 034006.	4.4	18
26	Manipulation of Magnetic Properties by Oxygen Vacancies in Multiferroic YMnO ₃ . Advanced Functional Materials, 2016, 26, 3589-3598.	14.9	45
27	Large-gap quantum spin Hall states in decorated stanene grown on a substrate. Physical Review B, 2015, 92, .	3.2	108
28	Band Engineering of Dirac Surface States in Topological-Insulator-Based van der Waals Heterostructures. Physical Review Letters, 2015, 115, 136801.	7.8	34
29	Robust Gapless Surface State and Rashba-Splitting Bands upon Surface Deposition of Magnetic Cr on Bi ₂ Se ₃ . Nano Letters, 2015, 15, 2031-2036.	9.1	33
30	Structural phase transition and electronic structure evolution in Ir _{1-x} Pt _x Te ₂ studied by scanning tunneling microscopy. Science Bulletin, 2015, 60, 798-805.	9.0	10
31	Chemical-Potential-Dependent Gap Opening at the Dirac Surface States of Bi_2Se_3 by Aggregated Substitutional Cr Atoms. Physical Review Letters, 2014, 112, 056801.	7.8	102
32	Sulfur immobilization and lithium storage on defective graphene: A first-principles study. Applied Physics Letters, 2014, 104, 043901.	3.3	18
33	Stable two-dimensional dumbbell stanene: A quantum spin Hall insulator. Physical Review B, 2014, 90, .	3.2	154
34	Realizing the quantum anomalous Hall effect in materials with in-plane magnetization. National Science Review, 2014, 1, 33-33.	9.5	0
35	Weak topological insulators induced by the interlayer coupling: A first-principles study of stacked Bi ₂ Te ₃ . Physical Review B, 2014, 89, .	3.2	46
36	Metallicity retained by covalent functionalization of graphene with phenyl groups. Nanoscale, 2013, 5, 7537.	5.6	9

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37	Large-Gap Quantum Spin Hall Insulators in Tin Films. <i>Physical Review Letters</i> , 2013, 111, 136804.	7.8	1,140
38	Electronic structure of silicene on Ag(111): Strong hybridization effects. <i>Physical Review B</i> , 2013, 88, .	3.2	186
39	Topological insulators in transition-metal intercalated graphene: The role of d electrons in significantly increasing the spin-orbit gap. <i>Physical Review B</i> , 2013, 87, .	3.2	43
40	Field-Effect Birefringent Spin Lens in Ultrathin Film of Magnetically Doped Topological Insulators. <i>Physical Review Letters</i> , 2013, 111, 116601.	7.8	15
41	Topology-Driven Magnetic Quantum Phase Transition in Topological Insulators. <i>Science</i> , 2013, 339, 1582-1586.	12.6	206
42	Design of strain-engineered quantum tunneling devices for topological surface states. <i>Applied Physics Letters</i> , 2012, 100, 131602.	3.3	26
43	Role of Ga-doping in iron-gallium alloy clusters. <i>Chinese Physics B</i> , 2012, 21, 027104.	1.4	1
44	Electronic and magnetic properties of boron nitride nanoribbons with topological line defects. <i>RSC Advances</i> , 2012, 2, 6192.	3.6	14